## **ELECTRICAL CHARACTERISTICS**

Part Number	Working Voltage (Vw)	Breakdown Voltage (Vb)	Clamping Voltage (Vc)	Peak Current (lp)	Transient Energy (Et)	Capac	oical citance C)
	Volt	Volt	Volt	Amp	Joule	pF	
	<50 μ A	1mA(DC)	2.5A,8/20 $\mu$ s	8/20 $\mu$ s	10/1000 $\mu$ s	1KHz	1MHz
JMV1206S120T801	12	14.0~18.3	34	150	0.6	800	-

- Vw- The max. steady state DC operating voltage of which varistor could maintain also not exceeding 50uA leakage current.
- Vb- The Voltage acrossed the device measured at 1mA DC current.
- Vc- The peak voltage acrossed the varistor measured at a specified pulse current and waveform.
- Ip- The max.peak current applied with specified wavefoem without any possibility of device fail.
- Et- The max. energy which dissipated with the specified waveform without any possibility of device fail.
- C The device capacitance measured with zero volt bias, 1.0Vrms and 1KHz / 0.5 V rms and 1 MHz.

MLV Storage condition→Temperature: ≤30°C/ Humidity:≤60% RH(Moisture Sensitivity Levels: 2a)
MLV Preservation period→ 6 months

## **External Dimension**

$\sim$ .	ь.	
( 'hin	I )ima	ension
OHIP	חוווע	

	inch(mm)			
Chip Size	L	W	Т	Α
1206	0.126±0.008	0.063±0.008	0.071max.	0.028max.
(3216)	(3.20±0.20)	(1.60±0.20)	(1.8max.)	(0.71max.)

